RQK0302GGDQA

Silicon N Channel MOS FET
Power Switching

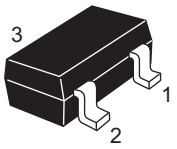
R07DS0305EJ0600
Rev.6.00
Jan 10, 2014

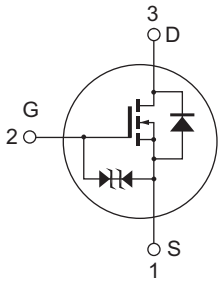
Features

- Low on-resistance
  $R_{DS(on)}$ = 92 mΩ typ (V_{GS} = 10 V, I_D = 1.3 A)
- Low drive current
- High speed switching
- 4.5 V gate drive

Outline

RENESAS Package code: PLSP0003ZB-A
(Package name: MPAK)





1. Source
2. Gate
3. Drain

Note: Marking is “GG”.

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	30	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	2.7	A
Drain peak current	$I_{D(Pulse)}$ Note1	5	A
Body - drain diode reverse drain current	I_{DR}	2.7	A
Channel dissipation	Pch Note2	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes: 1. PW ≤ 10 µs, duty cycle ≤ 1%
2. When using the glass epoxy board (FR-4: 40 × 40 × 1 mm)

Electrical Characteristics

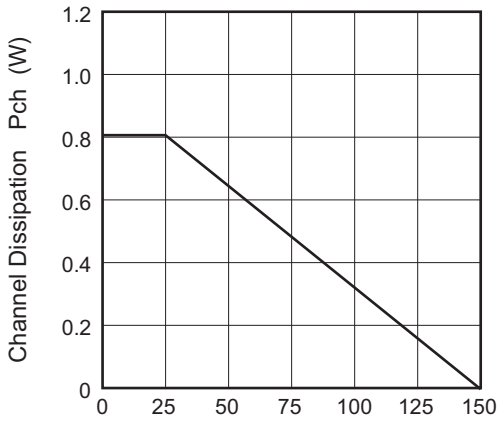
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	—	—	V	I_D = 10 mA, V_{GS} = 0
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	I_G = ±100 µA, V_{DS} = 0
Gate to source leak current	I_{GSS}	—	—	±10	µA	V_{GS} = ±16 V, V_{DS} = 0
Drain to source leak current	I_{DSS}	—	—	1	µA	V_{DS} = 30 V, V_{GS} = 0
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	V_{DS} = 10 V, I_D = 1 mA
Drain to source on state resistance	$R_{DS(on)}$	—	92	115	mΩ	I_D = 1.3 A, V_{GS} = 10 V Note3
	$R_{DS(on)}$	—	122	171	mΩ	I_D = 1.3 A, V_{GS} = 4.5 V Note3
Forward transfer admittance	$\|y_{fs}\|$	2.1	3.5	—	S	I_D = 1.3 A, V_{DS} = 10 V Note3
Input capacitance	Ciss	—	175	—	pF	V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz
Output capacitance	Coss	—	34	—	pF	
Reverse transfer capacitance	Crss	—	15	—	pF	
Turn - on delay time	$t_{d(on)}$	—	9.5	—	ns	I_D = 1 A, V_{GS} = 10 V, R_L = 10 Ω, Rg = 4.7 Ω
Rise time	t_r	—	37	—	ns	
Turn - off delay time	$t_{d(off)}$	—	38	—	ns	
Fall time	t_f	—	8.2	—	ns	
Total gate charge	Qg	—	3.3	—	nC	V_{DD} = 10 V, V_{GS} = 10 V, I_D = 2.7A
Gate to source charge	Qgs	—	0.6	—	nC	
Gate to drain charge	Qgd	—	0.5	—	nC	
Body - drain diode forward voltage	V_{DF}	—	0.9	—	V	I_F = 1.5 A, V_{GS} = 0 Note3

Notes: 3. Pulse test

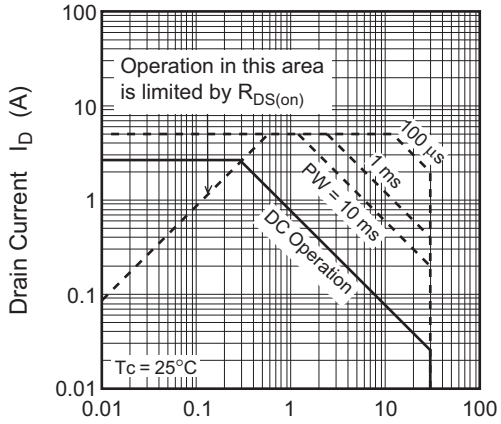
Main Characteristics

Maximum Channel Power Dissipation Curve

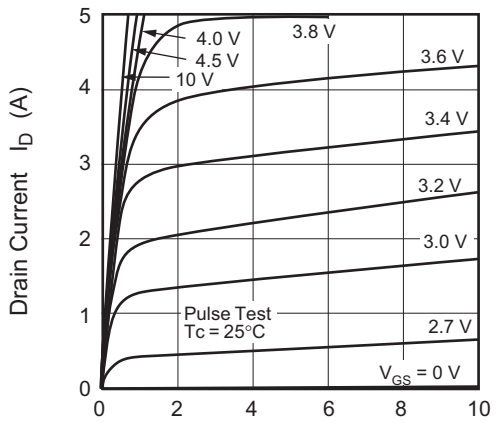


*When using the glass epoxy board (FR-4: 40 × 40 × 1 mm)

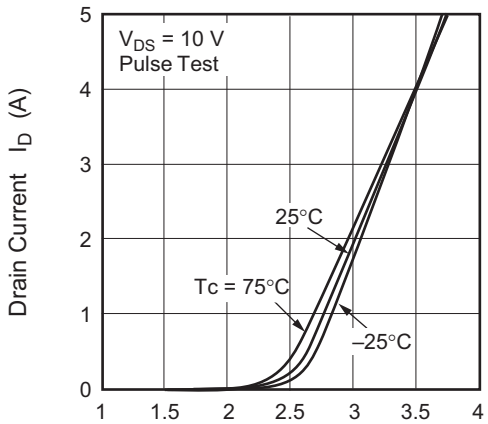
Maximum Safe Operation Area



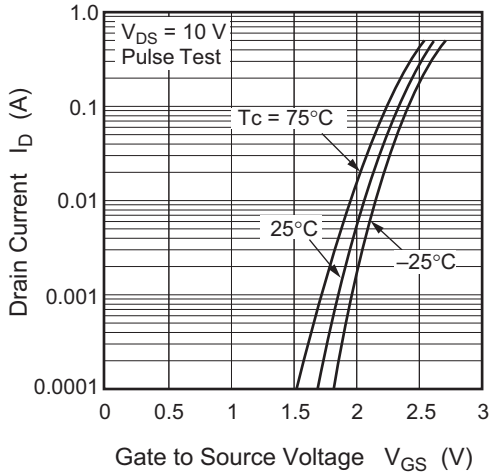
Typical Output Characteristics



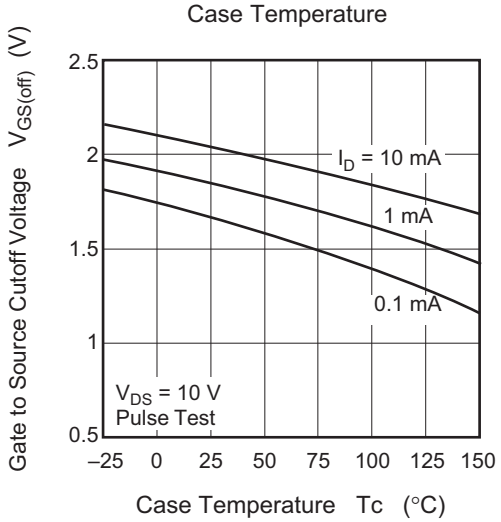
Typical Transfer Characteristics (1)



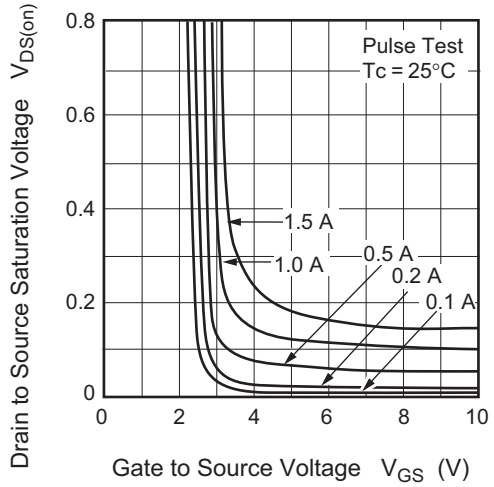
Typical Transfer Characteristics (2)



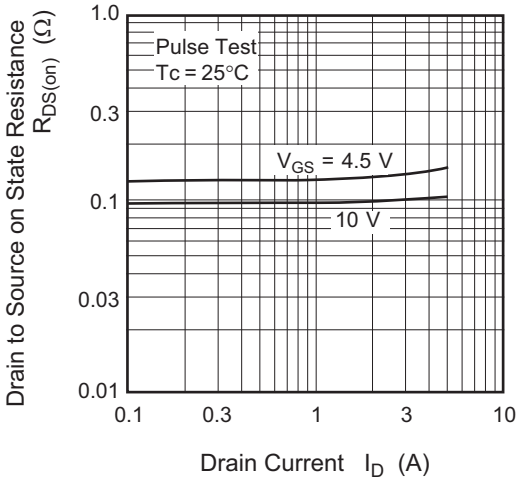
Gate to Source Cutoff Voltage vs. Case Temperature



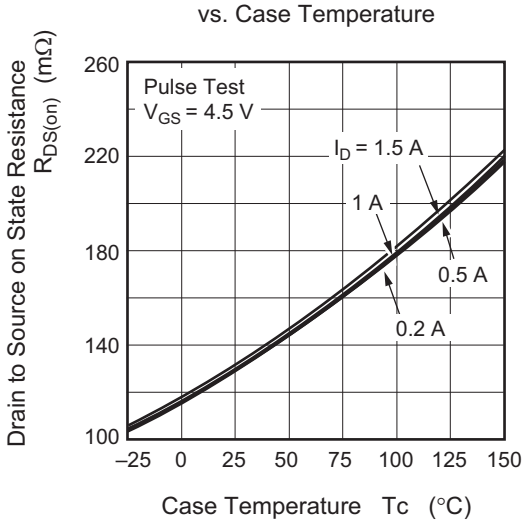
Drain to Source Saturation Voltage vs. Gate to Source Voltage



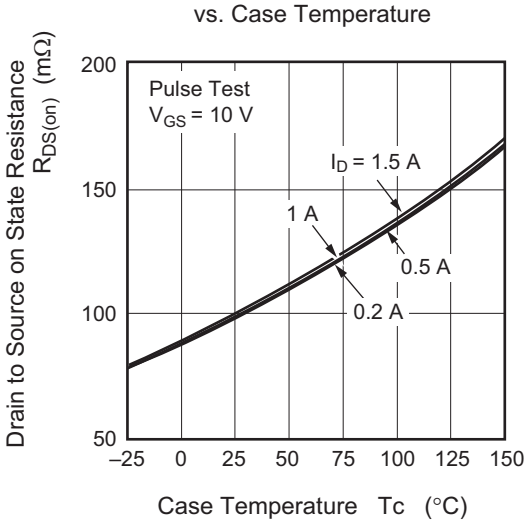
Static Drain to Source on State Resistance vs. Drain Current



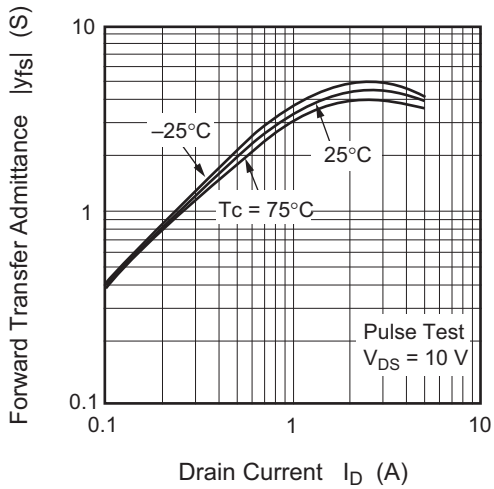
Static Drain to Source on State Resistance vs. Case Temperature



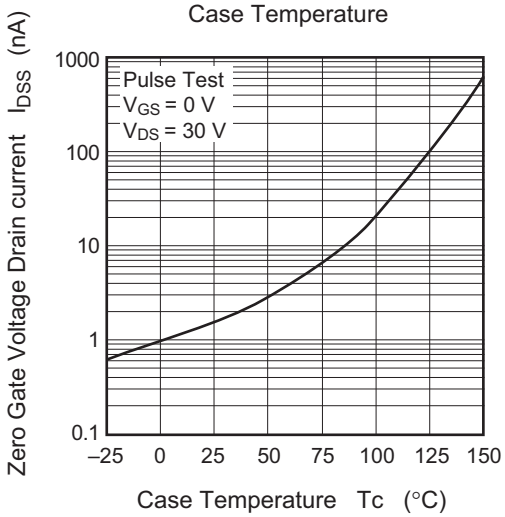
Static Drain to Source on State Resistance vs. Case Temperature



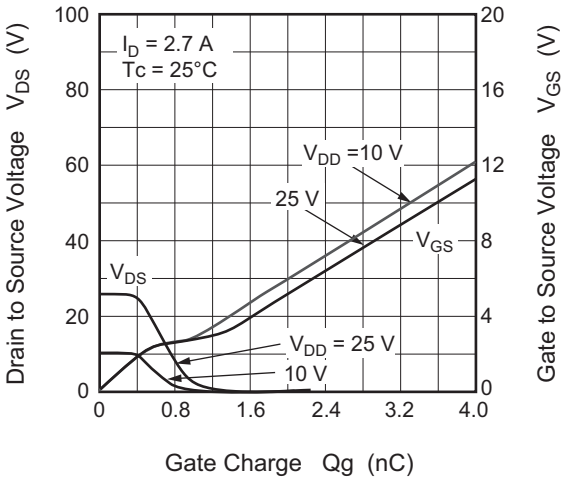
Forward Transfer Admittance vs. Drain Current



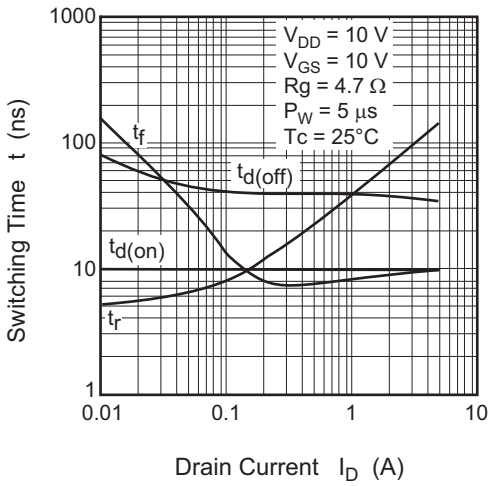
Zero Gate Voltage Drain current vs. Case Temperature



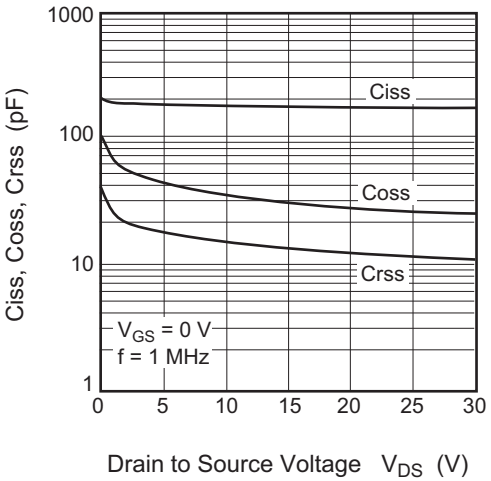
Dynamic Input Characteristics



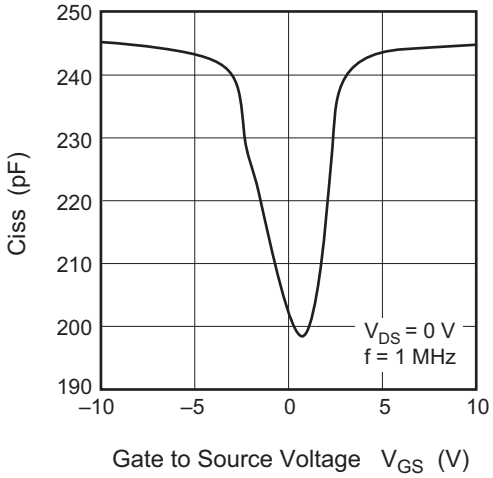
Switching Characteristics



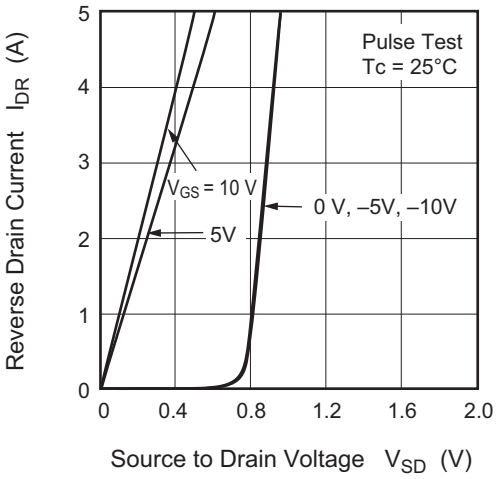
Typical Capacitance vs.
Drain to Source Voltage



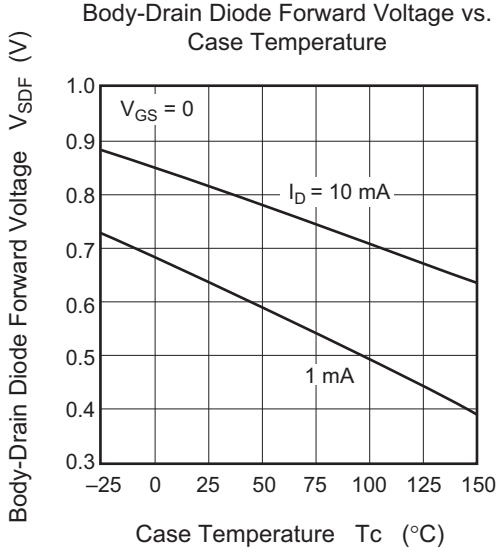
Input Capacitance vs.
Gate to Source Voltage



Reverse Drain Current vs.
Source to Drain Voltage

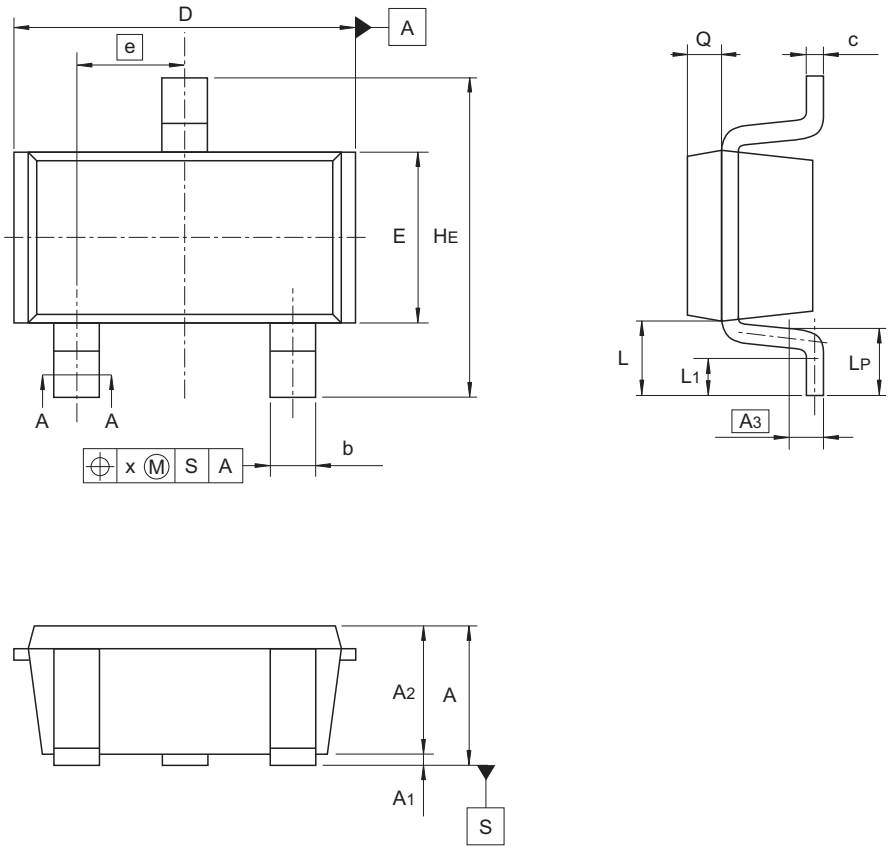


Body-Drain Diode Forward Voltage vs.
Case Temperature



Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011



Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
A	1.0	—	1.3
A_1	0	—	0.1
A_2	1.0	1.1	1.2
$\boxed{A_3}$	—	0.25	—
b	0.35	0.4	0.5
c	0.1	0.16	0.26
D	2.7	—	3.1
E	1.35	1.5	1.65
$\boxed{e}$	—	0.95	—
H_E	2.2	2.8	3.0
L	0.35	—	0.75
L_1	0.15	—	0.55
L_P	0.25	—	0.65
x	—	—	0.05
Q	—	0.3	—

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RQK0302GGDQATL-H	3000 pcs.	ϕ178 mm reel, 8 mm Emboss taping

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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 301, Tower A, Central Towers, 555 LanGao Rd., Putuo District, Shanghai, China
Tel: +86-21-2226-0888, Fax: +86-21-2226-0999

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd.
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
12F., 234 Teheran-ro, Gangnam-Gu, Seoul, 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141

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